Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	14	nanoparticle with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 13:54
S2	0	nanorod with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:50
S3	2	nanorods with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 11:44
S4	0	nanoparticle with floating near gate same metal near migration	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:53
S5	0	nanoparticles with floating near gate same metal near migration	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:53
S6	1	nanoparticles with floating near gate and metal near migration	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:54
S7	0	nanoparticles with floating near gate same barrier	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:55
S8	29	nanoparticles with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:57

S9	77	nanoparticles and floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:42
S10	33658	nanorodsand floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR·	OFF	2006/03/27 07:57
S11	7	nanorods and floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 07:59
S12	25	quantum near dots with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:15
S13	0	nanparticles with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:15
S14	0	nanparticle with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:15
S15	14	nanoparticle with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:15
S16	29	nanoparticles with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:23
S17	1	2005-088626.NRAN.	DERWENT	OR	OFF .	2006/03/27 08:18

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S18	4	nanoparticle\$1 and nanorod\$1 and nanowire\$1 and floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:26
S19	8	nanorod\$1 and floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:36
S20		EEPROM and nanoparticle\$1 and nanorod\$1 and nanowire\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF.	2006/03/27 08:29
S21	13	("5043940" "5434825" "6222762" " 6275419" "6317363" "6317364" "65 77532" "6586785" "6723606").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:36
S22	0	nanowire with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:42
S23	2	nanowires with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:43
S24	102	nanowires with memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:52
S25	96	nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 08:54

S26	69	nanocrystal with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF .	2006/03/27 08:55
S27	168	nanocrystal\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 08:55
S28	6	threshold with voltage with nanoparticle	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2006/03/27 10:40
S29	22	threshold with voltage with nanocrystal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:42
S30	20	threshold with voltage with nanowire\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:42
S31	2	threshold with voltage with nanowire\$1 same shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:43
S32	0	threshold with voltage with nanorod\$1 same shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF ,	2006/03/27 10:43
S33	0	threshold with voltage same nanorod\$1 with shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:43

S34	3	threshold with voltage same nanowire\$1 with shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:43
S35	1	threshold with voltage same nanoparticle\$1 with shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 10:43
S36	111	multi near state with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:26
S48	1951	(257/40).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:27
S49	335	S48 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:35
S50	0	S48 and sub near mono	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:35
S51	16	sub near mono near layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:52
S52	28	three near charge near state\$1 andnonvolatile	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:52

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S53	4	three near charge near state\$1 and nonvolatile	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:53
S54	1030	charge near state\$1 and nonvolatile	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:53
S55	5	charge near state\$1 same nonvolatile and nanocrystals	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2006/03/27 11:54
S56	2	charge near state\$1 same nonvolatile same nanocrystals	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:55
S57	0	charge near state\$1 same nonvolatile same quantum near dots	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:55
S58	26	nonvolatile same quantum near dots	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:25
S59	3	nonvolatile same quantum near dots same states	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:55
S60	26	nonvolatile same quantum near dots	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:56

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S61	0	sadd.in. and ("motor.as" frescale.as.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:56
S62	0	sadd.in. and (motor.as. frescale.as.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 11:56
S63	0	sadd.in. and moto.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:57
S64	0	sadd.inv'. and moto.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:57
S65	0	sadd.inv. and moto.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 11:57
S66	54	sadd.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:06
S67	1	nanoclusters with nanorods and nanowires	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 12:07
S68	13	sadd.inv. and nanocrystals	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 12:25

S69	52	nonvolatile same nanocrystals	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:28
S70	2	nonvolatile same nanocrystals and shell	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:17
S71	2154021	nanocrystals with shell with threshold voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:29
S72	0	nanocrystals with shell with threshold near voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:30
S73	0	nanocrystals with shell same threshold near voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:30
S74	0	nanocrystals same shell same threshold near voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:31
S75.	5	nanocrystals same shell same voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:31
S76	88	nanocrystals same shell with size	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 12:31

S77	39	nanocrystals with shell with size	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:32
S78	25	nanocrystals with shell with size and injection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 12:32
S79	0	nanocrystals with shell with size with injection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:33
S80		nanocrystals with shell with size same injection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:34
S81	0	quantum near dots with shell with size same injection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:33
S82	2	nanocrystals with passivation with size same injection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 12:35
S83	0	nanocrystals with passivation with size same voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:35
S84	9	nanocrystals with passivation with size	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:35

S85	29	nanocrystals with shell same thick\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:36
S86	54	nanocrystals with shell same thick\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 12:36
S87	0	quantum near rod with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 13:55
S88	0	quantum near rod\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 13:55
S89	0	quantum near rod\$1 same floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 13:55
S90		nanorods same floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:17
S91	5	nonvolatile same nanorods	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:18
S92	99	nonvolatile same nanotube\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2006/03/27 15:20

S93	13	floating near gate same nanotube\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:31
S95	33	gate with nanotube\$1 and mos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:31
S96	88	floating near gate same nanocrystal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:31
S97	192	floating near gate same nanocrystal\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:35
S98	0	floating near gate same nanocrystal\$1 and blokade	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 14:32
S99	14	floating near gate same nanocrystal\$1 and blockade	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:33
S10 0	2	floating near gate same nanostructure\$1 and blockade	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:33
S10 1	9	floating near gate same nanocrystal\$1 and multi near bit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 14:39

S10 2	59	floating near gate same nano\$8 and multi near bit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:43
S10 3	792	floating near gate same nano\$8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 14:43
S10 4	486	floating near gate with nano\$8	US-PGPUB; USPAT; . USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:04
S10 5	336	S104 and metal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:04
S10 6	96	floating near gate with nano\$8 with metal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:07
S10 7	14	floating near gate with nano\$8 with metal with nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:08
S10 8	14	floating near gate with nano\$10 with metal with nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:09
S10 9	. 46	floating near gate with nano\$10 with nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 15:09

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S11 0	0	nonvolatile with nanorods	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:20
S11 1	1	nonvolatile with nanorod	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:21
S11 2	0	nonvolatile with nanowire	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:21
S11 3	12	nonvolatile with nanowires	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 15:29
S11 4	2528	duan.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:24
S11 5	19	duan.inv. and xiangfeng.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:24
S11 6	90	nonvolatile with nanotube\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 15:30
S11 7	7	nonvolatile with nanotube\$1 same source same drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/27 15:31

S11 8	92	nonvolatile with nanotube\$1 andsource same drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	OFF	2006/03/27 15:32
S11 9	33	nonvolatile with nanotube\$1 and source same drain	IBM_TDB US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:05
S12 0	2	("20060011972").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:08
S12 1	0	EPROM same nanorod	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:08
S12 2	• 0	EPROM same nanorod\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:08
S12 3	0	EPROM same nanowire	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 16:08
S12 4	0	"1"\$EPROM same (nanowire\$1 nanorod\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:09
S12 5	0	EEPROM same (nanowire\$1 nanorod\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:09

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S12 6	10	floating near gate same (nanowire\$1 nanorod\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:11
S12 7	13	floating near gate same (nanotube\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:11
S12 8	53570	Eprom gate same (nanotube\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 16:11
S12 9		Eprom same (nanotube\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR T	OFF	2006/03/27 16:14
S13 0	6	EEprom same (nanotube\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:15
S13 1	13	floating near gate same (nanotube\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:16
S13 2	2	nano near floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:17
S13 3	80	nano with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR.	OFF	2006/03/27 16:26

S13 4	13	("5043940" "5434825" "6222762" " 6275419" "6317363" "6317364" "65 77532" "6586785" "6723606").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:29
S13 5	0	S134 and nanorods	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:29
S13 6	0	S134 and nanorod	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:29
S13 7	0	S134 and nanowire	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:30
S13 8	62	nanowire\$1 with nanorod\$1 with nanoparticle\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:42
S13 9	15	S138 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:38
S14 0	193	nanowire\$1 with nanorod\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:42
S14 1	45	nanowire\$1 with nanorod\$1 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:43

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S14 2	28	nanowire\$1 with nanorod\$1 and memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 17:09
S14 3	17	nanowire\$1 with nanorod\$1 and memory and nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 16:47
S14 4	88	nanorod\$1 and memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/27 17:43
S14 5	10	nanorod\$1 same gate and memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 17:11
S14 6	94	nanowire\$1 same gate and memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:35
S14 7	2	10/670670	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 17:14
S14 8	1008	(nanotube nano near tube) and memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 17:44
S14 9	349	(nanotube nano near tube) same memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/27 17:44

S15 0	177	nanowire\$1 same memory not nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:43
S15 1	2	("20040144972").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:36
S15 2	1	"10962972"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:46
S15 3	1	(NW nano near wire) with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:47
S15 4	2	nanowire\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:48
S15 5	10	nanowire\$1 same floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:51
S15 6	2481214	WO 02/17362	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 06:52
S15 7	42	"WO 02/17362"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 07:28

S15 8 ·	2	("6333214").PN.	US-PGPUB; USPAT; USOCR;	OR	OFF	2006/03/28 07:42
			EPO; JPO; DERWENT; IBM_TDB		,	
S15 9	5	nanocrystal\$1 with floating near gate and multibit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 07:45
S16 0	0	nanocrystal\$1 with floating near gate and coloumb near blockade	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 07:45
S16 1	168	nanocrystal\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 07:49
S16 2	2	nanorods with floating near gate and Coulomb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 07:48
S16 3	, 9	nanocrystal\$1 with floating near gate and multi near bit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF .	2006/03/28 07:51
S16 4	. 13	nanocrystal\$1 with floating near gate and Coulomb	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/28 07:52
S16 5	5	nanocrystal\$1 with floating near gate and Coulomb and multi near bit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/28 07:52
S16 6	11	("6090666" "6166401" "6344403").PN. OR ("6586785"). URPN.	US-PGPUB; USPAT; USOCR	OR .	OFF	2006/03/28 07:58

S16 7	0	metal near miration and quantum near dots	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 07:59
S16 8	, 5	metal near migration and quantum near dots	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 08:03
S16 9	7	flagan.inv. and nanoparticles	US-PGPUB; USPAT; USOCR	OR .	OFF	2006/03/28 08:34
S17 0	. 8	nanoparticle\$1 with injection with voltage	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 08:35
S17 1	3	(nanoparticle\$1 quantum near dot\$1 nanocrystal\$1) with injection with voltage with size	US-PGPUB; USPAT; USOCR	OR	OFF ·	2006/03/28 08:36
S17 2	56	(nanoparticle\$1 quantum near dot\$1 nanocrystal\$1) with voltage with size	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 08:49
S17 3	2	("6124188" "6586288").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 08:50
S17 4	1	10/877232	US-PGPUB; USPAT; USOCR	OR .	OFF	2006/03/28 09:24
S17 5	174	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 09:26
S17 6	0	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size) with voltage	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 09:26
S17 7	0	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size) with charge	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 09:26
S17 8	173	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:27
S17 9	1	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size) with injection not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 09:28
S18 0	. 9	atwater inv. and nanocrystals	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:23
S18 1	7	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size)same oxide not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:52

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S18 2	7	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size radius)same oxide not nanosys. as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:25
S18 3	742	(nanocrystal\$1 nanoparticle\$1) with (thickness size radius)same oxide not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:25
S18 4	346	(nanocrystal\$1 nanoparticle\$1) with (thickness size radius)with oxide not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:26
S18 5	8	(nanocrystal\$1 nanoparticle\$1) with (thickness size radius)with oxide same voltage not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:26
S18 6	4	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size)with (Si silicon) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:28
S18 7	12	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size)same(Si silicon) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:31
S18 8		(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size radius diameter)same(Si silicon) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:46
S18 9	8	(nanocrystal\$1 nanoparticle\$1) with (passivation shell)with (injection voltage) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:35
S19 0	8	(nanocrystal\$1 nanoparticle\$1) with (injection voltage) and multi near bit not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:38
S19 1	93	(nanocrystal\$1 nanoparticle\$1 nano\$) with (injection voltage) and multi near bit not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:40
S19 2	95	(nanocrystal\$1 nanoparticle\$1 nano\$ quantum near dot\$1) with (injection voltage) and multi near bit not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:43
S19 3	23	sadd.inv.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:43
S19 4	75	(nanocrystal\$1 nanoparticle\$1 nano\$) with (passivation shell\$1) with (thickness size radius diameter)same(Si silicon) not nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:48
S19 5	. 82	(nanocrystal\$1 nanoparticle\$1 nano\$) with (passivation shell\$1) with (thickness size radius diameter)same(Si silicon)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:48

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	S19 6	7	(nanocrystal\$1 nanoparticle\$1 nano\$) with (passivation shell\$1) with (thickness size radius diameter)same(Si silicon) and nanosys.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 10:49
	S19 7	9	(nanocrystal\$1 nanoparticle\$1) with (passivation shell) with (thickness size)with vary\$3	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 11:12
	S19 8	10	(nanocrystal\$1 nanoparticle\$1) with (passivation shell encapsulat\$4) with (thickness size)with vary\$3	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 11:15
	S19 9	23	sadd.inv.	US-PGPUB; USPAT; USOCR	OR ·	OFF	2006/03/28 11:15
	S20 0	254	(nanocrystal\$1 nanoparticle\$1) with (passivation shell encapsulat\$4) with (thickness size)	US-PGPUB; USPAT; USOCR	OR .	OFF	2006/03/28 12:09
	S20 1	6	(nanocrystal\$1 nanoparticle\$1) with (passivation shell encapsulat\$4) with (thickness size)with oxide	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 11:15
	S20 2	0	PCT/US05/07709	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 11:44
	S20 3	337	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 12:09
	S20 4	0	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size) with voltage	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 12:09
•	S20 5	2	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size) same voltage	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 12:10
	S20 6	10	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size) same inject\$3	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 12:12

S20 7	40	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size) same (electron\$1 hole\$1)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 12:53
S20 8	384	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size radius diameter)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:09
S20 9	9	("5043940" "5434825" "6222762" " 6275419" "6317363" "6317364" "65 77532" "6586785" "6723606").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 14:42
S21 0	2	S209 and shell	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:08
S21 1	58	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1) with (passivation shell encapsulat\$4) with (thickness size radius diameter) and memory	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:58
S21 2	60 .	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1 nanoelement\$1) with (passivation shell encapsulat\$4) with (thickness size radius diameter) and memory	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:35
S21 3	2	(nanoelement\$1) with (passivation shell encapsulat\$4) with (thickness size radius diameter) and memory	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:45
S21 4	2159	P-Mos	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 13:45
S21 5	100	(nanocrystal\$1 nanoparticle\$1 nanocluster\$1 quantum near dot\$1 nanodot\$1 nanoelement\$1) same (passivation shell encapsulat\$4) with (thickness size radius diameter) and memory	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 14:14
S21 6	149	kim.inv. and nanoparticles	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 14:16
S21 7	31	kim.inv. and nanocrystals	US-PGPUB; USPAT; USOCR	OR .	OFF	2006/03/28 14:16
S21 8	95	kim.inv. and quantum near dots	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 14:27

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S21 9	1953	(257/40).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:28
S22 0	1953	(257/40).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:28
S22 1	45	S220 and memory and functional near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF ·	2006/03/28 14:32
S22 2	1	S220 and memory and functional near group same (nanoparticle\$1 nanodot\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:37
S22 3	379	functional near group same (nanoparticle\$1 nanodot\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:39
S22 4	20	functional near group same (Si silicon)with(nanoparticle\$1 nanodot\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:40
S22 5	3	S209 and functional	US-PGPUB; USPAT; USOCR	OR	OFF	2006/03/28 14:42
S22 6	1	memory and functional near group same (quantum near dots nanoparticles nanocrystals) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:45
S22 7	1	memory and spacer near group same (quantum near dots nanoparticles nanocrystals) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/28 14:46

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S22 8	1	memory and spacer near group same (quantum near dots nanoparticle! nanocrystal\$1 nanocluster\$1) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:46
S22 9	1	memory and spacer near group same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR -	OFF	2006/03/28 14:46
S23 0	2	spacer near group same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:47
S23 1	76	functional near group same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:49
S23 2	0	functional near group same Si near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) same (spacing distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:49
S23 3	0	spacer near group same Si near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 14:49
S23 4	0	spacing near group same Si near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:49
S23 5		functional near group same (Si silicon) near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/28 14:50

S23 6		tail\$1 same (Si silicon) near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 14:51
S23 7	25	(spacing distance) same (Si silicon) near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 15:04
S23 8	0	(spacer near group) near (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:04
S23 9	. 10	(spacer near group) with (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:05
S24 0	11	(spacer near group) with (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:10
S24 1	876	hole with confinement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:13
S24 2	5846	CMOS and floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:24
S24 3	876561	EEPROM array	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:24

S24 4	1610	EEPROM near array	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF .	2006/03/28 15:24
S24 5	2	"20020074565"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:48
S24 6	0	nanorods with nanoparticles with naowires	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:29
S24 7	0	nanorod with nanoparticle with naowire	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:30
S24 8	60	nanorods with nanoparticles with nanowires	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:30
S24 9	22	nanorods with nanoparticles with nanowires and nanosys.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:31
S25 0	. 2	"20050201149"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:31
S25 1	94	spacer near group with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:49

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S25 2	42	spacer near group with silicon and soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:49
S25 3	872166	spacer near group with silicon asame' soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:50
S25 4	3	spacer near group with silicon same soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:50
S25 5	0	spacer near group with si same soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:50
S25 6	36	spacer near group with si and soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:52
S25 7	-1	spacer near group with silicon same head and soluble	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:52
S25 8	0	(functational near group) with (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:56
S25 9	0	(functational near group) same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:56

S26 0	0	(functational near group) same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near3 (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:56
S26 1	0	(functational near group) same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near6 (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 15:56
S26 2	2	(functional near group) same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:00
S26 3	0	(spacer near group) same (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) near (silicon si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:03
S26 4	0	functioalized with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:03
S26 5	0	functioalized with si	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 16:03
S26 6	38	functionalize with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:03
S26 7	13	functionalize with silicon and spacer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2006/03/28 16:03

S26 8	1	functionalize with silicon same spacer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 16:04
S26 9	23	functionalize\$1 with silicon with nanoparticle\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:07
S27 0	0	functionalize\$1 with silicon with nanoparticle\$1 and spacer near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:07
S27 1	12	functionalize\$1 with silicon with nanoparticle\$1 and spacer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:08
S27 2	398095	spacer group with carbon near nanotube	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:08
S27 3	0	spacer near group with carbon near nanotube	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:08
S27 4	0	spacer near group with carbon near nanoparticle	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:08
S27 5	0	spacer near group with carbon near nanowire	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:09

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S27 6	. 5	(spacer near group) with (quantum near dot\$1 nanoparticle\$1 nanocrystal\$1 nanocluster\$1) and silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:21
S27 7	0	gold with nanoparticle with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:22
S27 8	2	gold with nanoparticle\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/03/28 16:22
S27 9	6	metal with nanoparticle\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2006/03/28 16:24
S28 0	7	metal with quantum near dot\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:27
S28 1	2	gold with quantum near dot\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:33
S28 2	4	"10142838"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:28
S28 3	1	"10/142838"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:28

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S28 4	0	CdS with quantum near dot\$1 with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:33
S28 5	0	CdS with nanoparticle with floating near gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:50
S28 6	3	11/018572	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	О R	OFF .	2006/03/28 16:57
S28 7	1723	functionalized with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:58
S28 8	0	functionalized with silicon with spacer near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:58
S28 9	1	functionalized with silicon same spacer near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:59
S29 0	0	functionalize with silicon same spacer near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/28 16:59
S29 1	36	functional with group with silicon same spacer near group	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB		OFF	2006/03/28 17:01

S29 2	.1	head with silicon same spacer near group	US-PGPUB; USPAT;	OR	OFF	2006/03/28 17:01
	·	. ,	USOCR; EPO; JPO; DERWENT; IBM_TDB			
S29 3	2 .	10/796413	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/29 07:20
S29 4	1187	doping with activation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/29 07:20
S29 5	42	doping with activation with anneal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/29 07:21